From orbital to Pauli-limited critical fields in granular aluminum films

Aviv Glezer Moshe^(D),^{1,*} Eli Farber,² and Guy Deutscher¹

¹Raymond and Beverly Sackler School of Physics and Astronomy, Tel Aviv University, Tel Aviv, Israel ²Department of Physics and Department of Electrical and Electronic Engineering, Ariel University, Ariel

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The temperature dependence of the perpendicular upper critical field of superconducting granular aluminum films has been measured for samples approaching the metal-to-insulator transition. Analysis of the results shows a shift from an orbital to a Pauli-limited critical field, which we propose is made possible by electron mass renormalization. In that regime, the critical field transition becomes of the first order, as predicted by Fulde, Ferrel, Larkin, and Ovchinikov. The phase-coherence length ξ_{phase} and the superconducting gap Δ obtained from the analysis are consistent with a Bardeen-Cooper-Schrieffer–Bose-Einstein condensate crossover region, which we propose is triggered by the Mott transition of the granular films.

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I. INTRODUCTION

The upper critical field of type-II superconductors is usually limited by orbital effects. It is reached when the cores of Abrikosov vortices, set by the coherence length, overlap. Another mechanism that can quench superconductivity is pair breaking by Pauli spin polarization. It has been observed in films thinner than the coherence length placed in a parallel field, thus avoiding the presence of vortices [1–7]. But in three-dimensional samples, the orbital limit is usually reached well before spin polarization becomes important, in which exceptions are exotic superconductors such as LiFeAs [8] and LiTi₂O_{4- δ} [9].

Granular superconductors appear to be another possible exception. At high normal-state resistivity values, their critical field saturates at a value suggesting Pauli limitation [10,11]. Here we study the transition from an orbital to a Pauli-limited critical field and determine their respective values.

Werthamer, Helfand, and Hohenberg (WHH) [12] have developed a theory of the upper critical field that includes both orbital and Pauli limitations. Their relative roles are determined by the value of the Maki parameter,

$$\alpha = \frac{3\mu_B}{e\tau_{\rm tr}v_F^2},\tag{1}$$

where τ_{tr} is the transport scattering time and v_F is the Fermi velocity. The transition from orbital to Pauli limitation occurs when alpha is approximately equal to 1.

By measuring the temperature dependence of the perpendicular upper critical field of granular aluminum films, and fitting it to the WHH theory, we have been able to determine how the Maki parameter varies close to the metal-to-insulator transition. Our key finding is that it increases with resistivity and becomes higher than unity near the transition, which is anomalously high value for a conventional type-II superconductor. The prediction [13,14] of a first-order transition at low temperature in that regime is consistent with our observations.

We show that the large value of the Maki parameter requires a reduced effective Fermi velocity, a key characteristic of a Mott transition [15]. This large value allows one to accurately determine both the values of the orbital limited critical field H_{c2}^{orb} and that of the Pauli-limited critical field H_P . One thus obtains both the value of the phase-coherence length ξ_{phase} and that of the superconducting gap Δ . We have found that the ξ_{phase} saturates down to about 6 to 7 nm, while the value of Δ remains at about 0.5 meV. Because at the same time the critical temperature goes down, the strong-coupling ratio $2\Delta/k_BT_c$ reaches a value of about 5. The behaviors of the phase-coherence length and of the strong-coupling ratio are consistent with a BCS-BEC crossover near the Metalinsulator (MI) transition [16].

II. EXPERIMENTAL AND METHODS

Granular aluminum thin films were prepared by thermal evaporation of clean Al pallets in a controlled O₂ pressure, where the base pressure of the vacuum chamber is $\sim 1 \times 10^{-7}$ Torr. The films were deposited onto liquid-nitrogen-cooled substrates, either on bare dielectrics [MgO or (LaAlO₃)_{0.3} – (SrAl_{0.5}Ta_{0.5}O₃)_{0.7} (LSAT)] or onto Hall bars patterned on Si/SiO₂ or Al₂O₃ substrates. Films with various degrees of grain coupling were obtained by varying the O₂ partial pressure in the range of $2-5 \times 10^{-5}$ Torr, while keeping the deposition rate about 5 ± 1 A/s, similar to previous work [17,18]. This results in pure Al grains, 2 nm in size, embedded in an insulating aluminum oxide [19,20]. For more details on the implication for the normal-state properties due to the small grain size, please see [21–23]. The films thickness is in the range of 40–100 nm.

Standard four-point resistivity measurements were performed with either a Keithley 6221 current source and Keithley 2182A nano-voltmeter or with a Stanford research

^{*}avivmoshe@mail.tau.ac.il

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FIG. 1. Temperature dependence of the resistivity, normalized to its value at 4.2 K, showing the SC transition. The legend corresponds to the sample number.

SR830 lock-in amplifier. The current values were in the range of $1 \mu A$ to 1 nA, depending on the sample resistance. Measurements were taken in a commercial Quantum Design PPMS, which enables us to cool down to a temperature of 0.4 K and apply magnetic fields up to 14 T. Two additional samples with normal-state resistivity of 452 and 3400 $\mu\Omega$ cm were measured in a commercial Oxford Instruments Triton 400 dilution refrigerator from 1 K to 50 mK and up to 7 T. The normalized resistivity curves for selected samples are shown in Fig. 1. We did not observe the long tails below the transition reported by Dynes [24,25], even for our most resistive samples, possibly because granular aluminum films deposited at low temperature are more homogeneous than those deposited at room temperature since they have a narrower grain-size distribution [19,20]. The critical temperature values are in good agreement with previous work on similar films [16,22,23].

Upper critical fields $H_{c2}(T)$ were obtained by analyzing isotherms of $\rho(H)$, the value of $H_{c2}(T)$ being defined as that where the resistivity has reached half its normal-state value. Examples of isotherms are shown in the Appendix figures.

Temperature dependences of the critical fields were analyzed in terms of the WHH theory [12], which yields a



FIG. 2. Temperature dependence of the upper critical field for several of the studied samples. The legend corresponds to the sample number. The data were fitted to Eq. (2). The inset shows part of the data from the main figure, but with bars which mark the value of the field where the resistance has decreased by 90 and 10 percent relatively to the normal-state value.

complete temperature dependence of the upper critical field H_{c2} of a bulk type-II superconductor with inclusion of Pauli spin paramagnetism and spin-orbit impurity scattering effects. The temperature dependence of H_{c2} in the dirty limit is given by

$$\ln \frac{1}{t} = \sum_{\nu = -\infty}^{\infty} \left\{ \frac{1}{|2\nu + 1|} - \left[|2\nu + 1| + \frac{\overline{h}}{t} + \frac{(\alpha \overline{h}/t)^2}{|2\nu + 1| + (\overline{h} + \lambda_{so})/t} \right]^{-1} \right\},$$
 (2)

where $t = T/T_c$, $\overline{h} = \frac{4}{\pi^2} H_{c2}(T) \frac{1}{|dH_{c2}/dT|_{T_c}T_c}$, α is the Maki parameter [26], and $\lambda_{so} = \hbar/3\pi k_B T_c \tau_{so}$ is the spin-orbit scattering constant. Details of the fitting method, lending values of α , Δ , and ξ , are given in the Appendix. Examples of fits are shown in Fig. 2 for selected samples.

TABLE I. Properties of the studied samples. The parameters α , H_{c2} (the critical field at T = 0), H_{c2}^{orb} , and H_P have been extracted by fitting to Eq. (2).

| ID | $\rho_{4.2K}^n$ ($\mu\Omega$ cm) | T_c (K) | α | H_{c2} (T) | H_{c2}^{orb} (T) | H_P (T) | ξ(0) (nm) |
|----|-----------------------------------|-----------------|---------------|-------------------|-----------------------------|---------------|-----------|
| 1 | 169 | 3.02 ± 0.05 | | 1.49 | 1.55 | | 14.5 |
| 2 | 250 | 3.05 ± 0.14 | | 2.04 | 2.10 | | 12.5 |
| 3 | 547 | 3.05 ± 0.07 | 0.69 ± 0.07 | 3.57 | 4.34 | 8.97 ± 0.61 | 8.7 |
| 4 | 973 | 2.99 ± 0.06 | 0.85 ± 0.08 | 4.13 | 5.43 | 9.06 ± 0.50 | 7.8 |
| 5 | 1157 | 2.77 ± 0.03 | 1.30 ± 0.03 | 4.08 | 6.71 | 7.31 ± 0.05 | 7.0 |
| 6 | 1687 | 2.62 ± 0.05 | 1.48 ± 0.03 | 3.98 | 7.13 | 6.80 ± 0.04 | 6.8 |
| 7 | 8300 | 2.33 ± 0.11 | 1.76 ± 0.09 | 3.91 | 7.92 | 6.38 ± 0.08 | 6.4 |
| 8 | 8820 | 2.27 ± 0.12 | 1.70 ± 0.03 | 3.87 | 7.50 | 6.36 ± 0.03 | 6.6 |
| 9 | 19000 | 1.81 ± 0.20 | | 3.83 ^a | | | |
| 10 | 452 | 3.04 ± 0.04 | | 3.59 | 3.71 | | 9.4 |
| 11 | 3400 | 2.37 ± 0.16 | 1.43 ± 0.07 | 4.19 | 7.32 | 7.26 ± 0.11 | 6.7 |

 $^{a}H_{c2}$ value as measured at 0.4 K.



FIG. 3. The orbital critical field H_{c2}^{orb} vs resistivity (circles) as obtained from fitting the data to WHH theory along a linear fit to the low-resistivity data.

III. RESULTS

The main parameters of the studied samples are summarized in Table I. The Maki parameter increases with resistivity, reaching values higher than unity at resistivities higher than 1000 $\mu\Omega$ cm. The error bars deserve a few comments. For H_P , and therefore for the gap and the strong-coupling ratio, they are large at intermediate resistivity values. It is only for resistivities higher than 1000 $\mu\Omega$ cm that we consider their values to be reasonably accurate. The coherence length saturates down to a value of about 6 to 7 nm. The value of the strong-coupling parameter is in the range of 5.

For the low-resistivity samples 1, 2, and 10, the temperature dependence of the critical field is in agreement with theory without taking into account the effect of spin polarization. But for samples having resistivity values higher than several-hundred $\mu\Omega$ cm, one can see from Fig. 2 that it is noticeably different from that of the lower-resistivity samples, particularly at low temperatures. Values of the Maki parameter larger than 1 are necessary to fit the data to the WHH theory for resistivity values larger than 1000 $\mu\Omega$ cm. Values of H_{c2}^{orb} are plotted in Fig. 3 as a function of the normal-state resistivity. At low resistivities, they increase linearly with ρ , as expected for a dirty type-II superconductor. At high resistivities, they saturate at about 7 to 8 T.

We note that for all of the samples, the fit yields $\lambda_{so} = 0$, which deserves a few remarks. The spin-orbit scattering time can be approximated by [27] $\tau_{so} \simeq \tau/(Z\alpha_f)^4$, where τ is the elastic scattering time, Z is the atomic number, and $\alpha_f \simeq 1/137$ is the fine-structure constant. Estimating τ from the relation $\rho\tau = 3.13 \times 10^{-14} \,\mu\Omega$ cm s for aluminum [28], we obtain, for the lowest resistivity measured sample, $\tau \simeq 1.9 \times 10^{-16}$ sec and therefore $\tau_{so} \simeq \tau \times 1.2 \times 10^4 \simeq 2.3 \times 10^{-12}$ sec. The expected spin-orbit parameter is then about $\lambda_{so} \sim 0.1$. However, as ρ changes over two orders of magnitude, we expect that so does λ_{so} . The fact that we can fit very well the data for all samples without spin-orbit suggests that the actual elastic scattering time τ is not changing much with increasing resistivity; we will return to this point later on.



FIG. 4. Resistivity magnetic field and temperature dependence of the samples 10 and 11, measured down to 50 mK. (a),(b) High-resistivity sample with $\rho_{4.2K} = 3400 \ \mu\Omega$ cm. (c),(d) Low-resistivity sample with $\rho_{4.2K} = 452 \ \mu\Omega$ cm. Note that in sharp contrast, the high-resistivity sample transition narrows dramatically as the temperature decreases. Note in (b) that in a narrow field range around 4.25 T, the resistivity goes through a minimum, at a temperature compatible with the occurrence of a maximum in $H_{c2}(T)$. This is where the transition changes from second to first order.

Isotherms measured from 1 K down to 50 mK for a sample with normal-state resistivity of $3400 \,\mu\Omega$ cm are shown in Fig. 4(a). Below 0.4 K, the transition becomes extremely sharp. The long tails seen at higher temperatures above the critical field are suppressed. The same behavior was reported by Tedrow and Meservey [7] on thin Al films in a parallel field configuration, which they attributed to a change from a second-order transition to a first-order one, as predicted by Fulde and Maki [29]. This change is accompanied by a suppression of the paraconductivity above the critical field, which for a three-dimensional sample in perpendicular field [29] is of the form $\sigma_{fl} \propto T/\sqrt{H - H_{c2}}$. The resistivity was fitted to the expression $\rho = \frac{1}{1/\rho_n + aT/\sqrt{H - H_{c2}(T)}}$, where ρ_n was chosen here as the value above the critical field at 50 mK and the fitting parameters are a and H_{c2} . The fitting range was limited down to a field value at which $\rho = 0.85\rho_n$. The extracted $H_{c2}(T)$ values from the fit are shown in Fig. 5(a), where one can see the expected downturn of $H_{c2}(T)$ (below ~ 0.7 K) as predicted by WHH for $\alpha > 1$, where a first-order transition is expected. Deviation from a linear dependence on T can be seen in Fig. 5(b), at magnetic fields close to $H_{c2}(T)$, where the paraconductivity becomes more sensitive to the anomalous H_{c2} temperature dependence. This is in sharp contrast to the excellent agreement at higher magnetic field values up to 5 T, where the temperature dependence of H_{c2} is negligible.

The same similarity is seen between their cooling curves and our own shown in Fig. 4(b), displaying a striking minimum at 4.25 T. By contrast, isotherms measured in the same range of temperature for a more metallic sample with normal-state resistivity of 452 $\mu\Omega$ cm show a regular shift of the transition down to the lowest temperature, as can be seen in Figs. 4(c) and 4(d). We conclude that granular films near the metal-insulator transition do undergo a first-order field-induced transition, in keeping with the large values of the Maki parameter that we have determined.

IV. DISCUSSION AND CONCLUSIONS

While, according to Eq. (1), the value of the Maki parameter can, in principle, be increased beyond 1 by reducing the transport scattering time, strong scattering generally leads to Anderson electron localization and destruction of superconductivity before this regime is reached. This is well documented for NbN_x, where scattering is increased by introducing nitrogen vacancies [30,31]. To discuss this point quantitatively, it is useful to rewrite Eq. (1) as

$$\alpha = \frac{3}{2k_F l},\tag{3}$$

where we have assumed that the effective mass of the electron is that of a free electron. Reaching values of α of the order of unity requires that the product $k_F l$ approaches unity. But in NbN_x [30–32] and other similar atomically disordered mate-



FIG. 5. Sample 11 paraconductivity analysis. (a) $H_{c2}(T)$ as extracted from fitting the $\rho(H)$ data to Fulde and Maki theory [29], as described in the text. (b) Conductivity σ vs temperature at different values of magnetic field. Circles are the data as extracted from the $\rho(H)$ curves and the thick lines are linear fits to the Fulde and Maki theory, $\sigma = \sigma_n + aT/\sqrt{H - H_{c2}(T)}$. σ_n was chosen as the intercept at the highest field measured (5 T) and was fixed for all fits.

rials such as MoN [33], superconductivity is then completely quenched. Therefore, Pauli limitation cannot be observed in that case.

But when a transition of the Mott type is approached, superconductivity is not so quickly destroyed because the density of states at the Fermi level remains unchanged [15,34]. The Fermi energy is reduced and the effective electronic mass is strongly enhanced [15]. The value of the Maki parameter must then take into account this enhancement factor. Even if $k_F l$ is smaller than unity, as is the case in granular aluminum [16], superconductivity persists and the Maki parameter can be larger than 1. The large value of the Maki parameter that we have found near the metal-to-insulator transition of granular aluminum is therefore an important confirmation that in this material, the transition is of the Mott type rather than of the Anderson type.

In fact, near the transition, the increase of the Maki parameter is driven by the renormalization of the Fermi energy rather



FIG. 6. Magnetic field dependence of the resistivity, showing $\rho(H)$ isotherms of four samples. Note that for the high-resistivity samples 6 and 8, the transition becomes narrow as the temperature decreases.

than by the decrease of the scattering time, which dominates far from the transition.

Since at the Mott transition the effective Fermi energy goes to zero, it becomes at some point of the same order of magnitude as the energy gap. Here, strong coupling is the result of the reduced Fermi energy. When it becomes of the same order as the gap, the number of Cooper pairs per coherence volume is of the order of unity. The transition region can be treated as a BCS-BEC crossover region. Theory predicts that in this region, the phase-coherence length, and hence the orbital critical field, saturates [35]. This is in agreement with the behavior that we observe. The value of about 5 that we have obtained for the strong-coupling parameter is also in fair agreement with that predicted in the BCS-BEC crossover region [16,36,37].

In conclusion, by studying the temperature dependence of the upper critical field of granular aluminum films and fitting it to the WHH theory, we have been able to determine the values of the Maki parameter, the Pauli field, and the phasecoherence length near the metal-to-insulator transition. The value reached by the Maki parameter is larger than one. This requires a strong mass renormalization factor. For the highestresistivity films, the transition becomes first order below a few 100 mK. These results are consistent with a Mott transition, not with an Anderson transition. The strong-coupling ratio derived from the values of the Pauli field and of the measured critical temperature reaches a value of about 5, while the phase-coherence length saturates to a value of about 6 to 7 nm. These findings are consistent with a BCS-BEC crossover regime. *Note added in proof.* Recently, we became aware of the possible relevance of a first-order transition to a recent work [38] showing that the performance of a granular aluminum quantum device remains unaffected by magnetic fields of up to 1 Tesla. We are grateful to Ioan Pop for making us aware of this.

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APPENDIX: DATA ANALYSIS OF $\rho(H)$ AND ADDITIONAL DATA

The fitting of the critical field data was done by first constructing a $H_{c2}(t)$ curve from Eq. (2) in the main text. This was done by solving it numerically for $H_{c2}(t)$ at each value of $t = T/T_c$, α , and $|dH_{c2}/dT|_{T_c}$. The reason we chose the slope near T_c as a fitting parameter is a lack of accurate data points near T_c for most of the samples. Utilizing MATLAB, the values of α and $|dH_{c2}/dT|_{T_c}$ were varied until the best fit was obtained, where the uncertainty of both fitting parameters was determined by a 95% confidence interval. Upon finding the best values, $H_{c2}(0)$ is found by evaluating Eq. (2) in the main text at $t \rightarrow 0$. Then, H_{c2}^{orb} and H_P can be retrieved by

$$H_{c2}^{\text{orb}} = \sqrt{1 + \alpha^2} H_{c2}(0),$$
 (A1)



FIG. 7. $\rho(H)$ isotherms of sample 11, zoomed into the regime $H > H_{c2}$. The arrow marks the direction of decreasing temperature.

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$$H_P(0) = \frac{\sqrt{2}}{\alpha} H_{c2}^{\text{orb}}(0).$$
 (A2)

The Pauli field gives access to the gap parameter

$$H_P = \frac{\Delta}{g^{1/2}\mu_B} \tag{A3}$$

and the orbital field to the coherence length

$$H_{c2}^{\text{orb}} = \frac{\Phi_0}{2\pi\xi^2}.$$
 (A4)

We have thus obtained the values of α , Δ , and ξ .

Isotherms of selected samples are shown in Fig. 6. Isotherms of sample 11, measured down to 50 mK, are shown in Fig. 7.

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